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B.E. / B.Tech. DEGREE EXAMINATION, NOV 2016

Third Semester

Electrical and Electronics Engineering

15UEE305 - SEMICONDUCTOR DEVICES AND CIRCUITS

(Regulation 2015)

	(Regulation 20	713)	
	Duration: Three hours Answer ALL Que		num: 100 Marks
	PART A - $(10 \times 1 = 1)$		
1.	The breakdown mechanism in a lightly dop condition is called	ed P-N junction under	reverse biased
	(a) Avalanche breakdown(c) Breakdown by tunneling	(b) Zener breakdown(d) High voltage breakd	lown
2.	In a full-wave rectifier without filter, the ripple is	factor is	
	(a) 0.482 (b) 1.21	(c) 1.79	(d) 2.05
3.	A transistor is a		
	(a) Current controlled current device(c) Voltage controlled current device	(b) Current controlled v(d) Voltage controlled v	•
4.	Which of the BJT configuration is suitable for in	mpedance matching	
	(a) Common Base Configuration(c) Common Collector Configuration	(b) Common Emitter Co(d) None of these	onfiguration
5.	A JFET is also called transistor.		
	(a) Bipolar	(b) Unijunction	
	(c) Uni polar	(d) None of these	

6.	A MOSFET operates in	_ mode.	
	(a) Depletion	(b) Enhancement	
	(c) Both (a) and (b)	(d) None of these	
7.	A negative feedback is employed in	1	
	(a) Oscillator (b) Amplif	fiers (c) Rectifiers (d) None of these
8.	The main advantage of a crystal osc	cillator is that its output is	
	(a) 50Hz to 60Hz	(b) Variable frequency	
	(c) Constant frequency	(d) DC	
9.	An Astable multivibrator has		
	(a) No Stable State	(b) One Stable State	
	(c) Two Stable States	(d) None of these	
10.	The negative clipper is that which r	emoves thehalf cycle of the	input voltage.
	(a) Positive (b) Negative	(c) Both (a) and (b) (d) None of these
	PART -	B (5 x $2 = 10$ Marks)	
11.	What is diffusion current?		
12.	State the relation between ' α ' and '	β' of a transistor.	
13.	What is Darlington pair?		
14.	Define CMRR of differential ampli	fier.	
15.	What is meant by hysteresis in Schr	mitt trigger?	
	PART -	$C (5 \times 16 = 80 \text{ Marks})$	
16.	(a) Explain the working of a PN June characteristics.	unction diode and Zener diode and	explain the V-I
		Or	
	(b) (i) Write a note on light emitt	ing diode with net sketches and give	its applications.
	(ii) Explain the temperature eff	Sects on PN junction diodes.	(8)

17.	(a)	Explain the input and output characteristics of BJT in CE configuration and derive the hybrid parameters. (16)
		Or
	(b)	(i) Explain the important characteristics of Opto coupler in electronic isolator circuits.
		(ii) Compare CE, CB and CC configurations of BJT. (8)
18.	(a)	Explain the construction and characteristics of enhancement MOSFET with neat sketch. (16)
		Or
	(b)	(i) Cascade amplifiers have high bandwidth. Validate this statement suitably. (6)
		(ii) Explain in detail the construction, operation and characteristics of N-channel JFET. (10)
19.	(a)	Explain the general characteristics of negative feedback amplifiers represent (i) Voltage series (ii) Voltage shunt (iii) Current series (iv) Current shunt feedback connection diagrammatically. (16)
		Or
	(b)	(i) Discuss in detail the common mode operation of differential amplifier with appropriate circuit diagram. (8)
		(ii) Explain the operation of RC phase shift oscillator. (8)
20.	(a)	Explain about any four types of clippers. (16)
		Or
	(b)	(i) Explain the operation of monostable multivibrator and state its applications. (8)
		(ii) Explain the working of UJT based saw tooth oscillator. (8)
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